## NSN 5962-01-276-9907

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-276-9907

view Online at https://aeiobasegroup.com/nsii/3902-01-270-3907
Body Length:
52.3 millimeters
Body Width:
14.7 millimeters
Body Height:
5.1 millimeters
Maximum Power Dissipation Rating:
500.0 milliwatts
Operating Tempurature Range:
+0.0/+70.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and burn in and programmable and w/clock
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
27 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Time Rating Per Chacteristic:
135.00 nanoseconds propagation delay time, low to high level output and 135.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Pal
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
40 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:

Yes - demil/mli

Fiig:

A458a0